SILICON RECTIFIER DIODES



Diffused silicon rectifier diodes in DO-4 metal envelopes, intended for power rectifier applications.

The series consists of the following types:

Normal polarity (cathode to stud): BYX42-300 to 1200. Reserve polarity (anode to stud): BYX42-300R to 1200R.

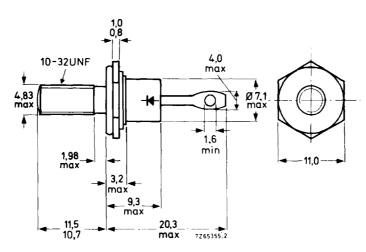
QUICK REFERENCE DATA

		BYX42-300(R)	600(R)	1200(R)
Repetitive peak reverse voltage	V_{RRM}	max. 300	600	1200 V
Average forward current	IF(AV)	max.	12	Α
Non-repetitive peak forward current	IFSM	max.	125	Α

MECHANICAL DATA

Dimensions in mm

DO-4



Net mass: 6 g Diameter of clearance hole: 5,2 mm Accessories supplied on request:

see ACCESSORIES section

Torque on nut: min. 0,9 Nm (9 kg cm) max. 1,7 Nm (17 kg cm)

Supplied with device: 1 nut, 1 lock washer Nut dimensions accross the flats: 9.5 mm

The mark shown applies to normal polarity types.



Products approved to CECC 50 009-020 available on request.

RATINGS	Limiting values	in accordance	with the Absolute	Maximum S	ystem (IEC 134)
---------	-----------------	---------------	-------------------	-----------	---------	----------

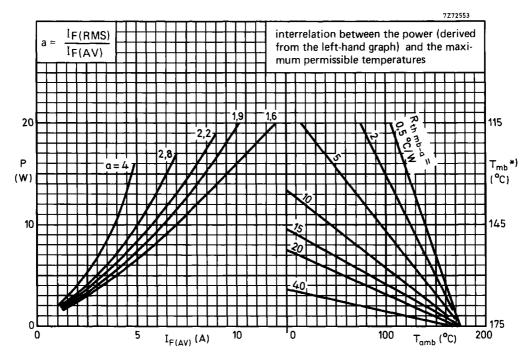
Non-repetitive peak reverse voltage (t \leq 10 ms)
$(\delta \le 0,01)$ V_{RRM} max. 300 600 1200 V Crest working reverse voltage V_{RWM} max. 200 400 800 V
KWM
Continuous reverse voltage V _R max. 200 400 800 V
Currents
Average forward current (averaged over any 20 ms period) up to T_{mb} = 115 °C $I_{F(AV)}$ max. 12 A at T_{mb} = 125 °C $I_{F(AV)}$ max. 10 A
R.M.S. forward current $I_{F(RMS)}$ max. 20 A
Repetitive peak forward current IFRM max. 60 A
Non-repetitive peak forward current (t = 10 ms; half sine-wave) T_j = 175 °C prior to surge; with reapplied V_{RWMmax}
Temperatures
Storage temperature $T_{\rm stg}$ -55 to +175 $^{\rm o}{\rm C}$
Junction temperature T_j max. 175 $^{\rm o}{\rm C}$
THERMAL RESISTANCE
From junction to ambient in free air $R_{th j-a} = 50 ^{\text{o}}\text{C/W}$
From junction to mounting base $R_{th j-mb} = 3 ^{\circ}\text{C/W}$
From mounting base to heatsink $R_{th mb-h} = 0.5$ °C/W
CHARACTERISTICS
Forward voltage at I _F = 15 A; T_i = 25 °C V_F < 1, 4 V^{-1})
Reverse current at $V_R = V_{RWMmax}$; $T_j = 125$ °C $I_R < 200 \mu$ A

MOUNTING INSTRUCTIONS

The top connector should neither be bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.

 $^{{\}color{red} 1}$) Measured under pulse conditions to avoid excessive dissipation.



*) $T_{mb}\text{-scale}$ is for comparison purposes only and is correct only for $R_{th\ mb\text{-}a} \leq 22~^{o}\text{C/W}$

